Optical Properties of Solids: Lecture 8

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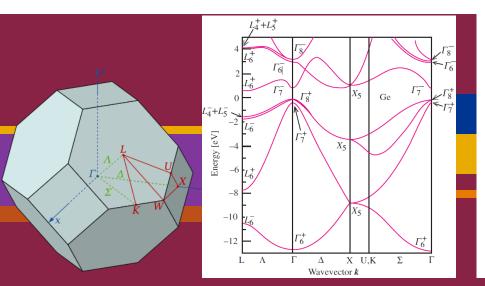
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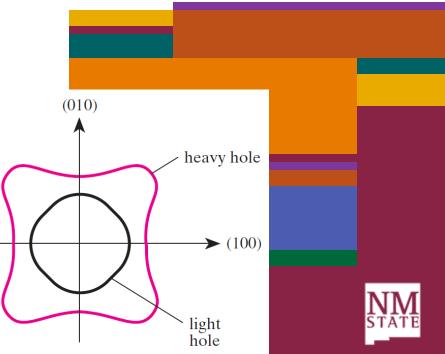
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Optical Properties of Solids: Lecture 7+8+9

- Electronic Band Structure
- Direct and indirect band gaps
- Empty lattice, pseudopotential, k.p band structures
- Optical interband transitions, Fermi's Golden Rule Absorption coefficient for direct and indirect gaps Tauc plot
- Van Hove singularities





References: Band Structure and Optical Properties

Solid-State Theory and Semiconductor Band Structures:

- Mark Fox, Optical Properties of Solids
- Ashcroft and Mermin, Solid-State Physics
- Yu and Cardona, Fundamentals of Semiconductors
- Dresselhaus/Dresselhaus/Cronin/Gomes, Solid State Properties
- Cohen and Chelikowsky, Electronic Structure and Optical Properties
- Klingshirn, Semiconductor Optics
- Grundmann, Physics of Semiconductors
- Ioffe Institute web site: NSM Archive <u>http://www.ioffe.ru/SVA/NSM/Semicond/index.html</u>

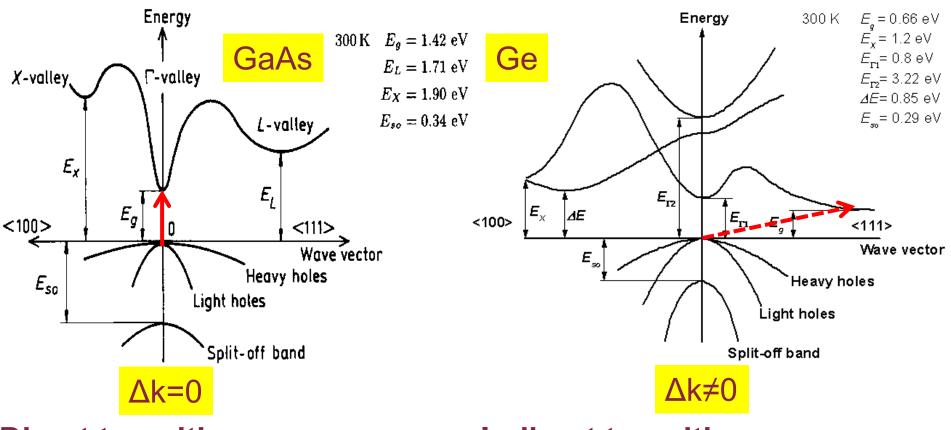


Outline

- **Band structure and optical interband transitions**
- Einstein coefficients, population inversion, optical gain, lasers Fermi's Golden Rule
- Joint density of states, optical mass
- Direct gap absorption in InAs, PbS, and InSb; Tauc plot
- Indirect gap absorption in Si and Ge
- Experimental techniques to measure absorption
- Van Hove singularities
- Critical points in the dielectric function
- Analytical lineshapes to fit Savitzky-Golay derivative
- Parametric oscillator model



Semiconductor Band Structures



Direct transition:

Initial and final electron state have **same** wave vector.

Indirect transition:

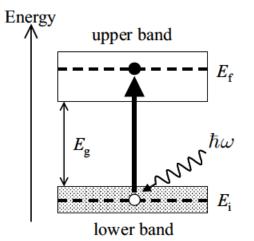
Initial and final electron state have **different** wave vector.



http://www.ioffe.ru/SVA/NSM/Semicond/index.html

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Optical Interband Transitions

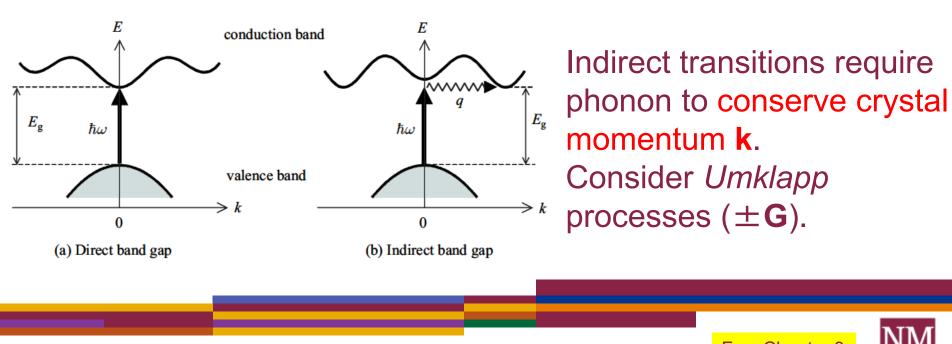


Absorption:

Incoming photon creates electron-hole pair **Recombination:**

Electron-hole pair creates a photon

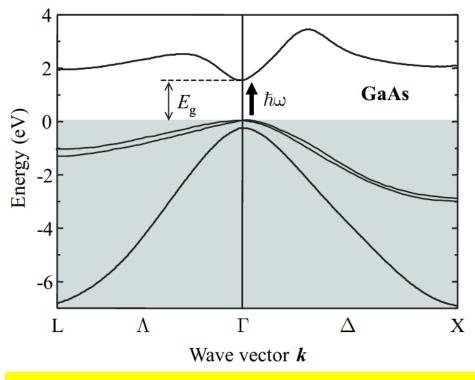
Energy and crystal momentum conserved (within Heisenberg uncertainty)



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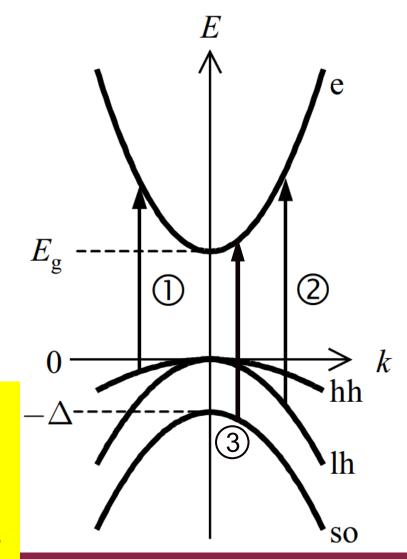
Fox, Chapter 3

Optical Interband Transitions in GaAs



Various transitions are possible. Consider non-parabolicity and warping.

How does absorption cross-section depend on energy and wave vector? How do we describe absorption and emission?



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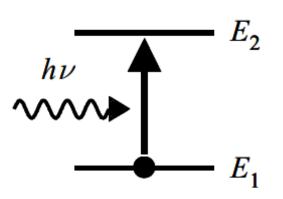
7

Einstein coefficients: Two-level system

(a) Emission (spontaneous)

 E_2

 E_1



(b) Absorption (stimulated) Conservation of energy, no broadening

$$\hbar\omega = E_2 - E_1$$

Lifetime:

$$\frac{A_{21}}{dt} = -A_{21}N_2$$

(Einstein did not know about fermions and Pauli exclusion in 1917.)

$$\frac{dN_1}{dt} = -B_{12}N_1u(\hbar\omega)$$

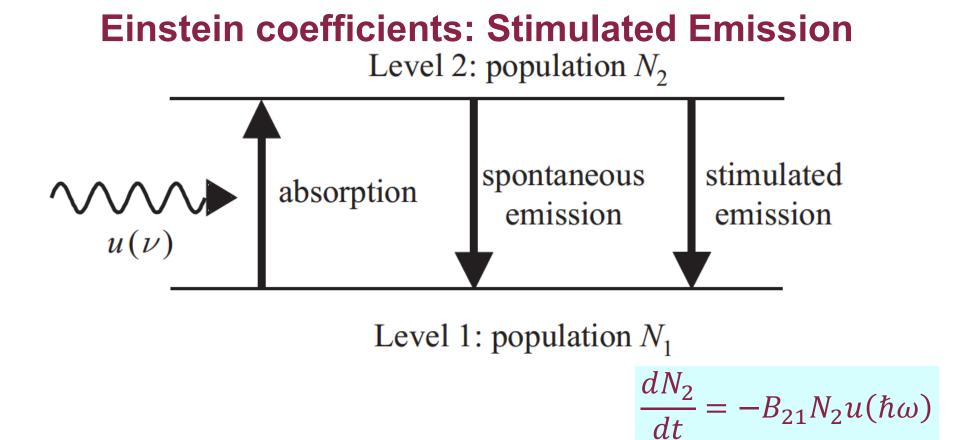
Paradox: For sufficiently high light intensity (or long lifetime), all electrons will end up in the excited state.

Fox, Appendix B R.C. Hilborn, Am. J. Phys. **50**, 982 (1982). A. Einstein, Phys. Z. **18**, 121 (1917).

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8

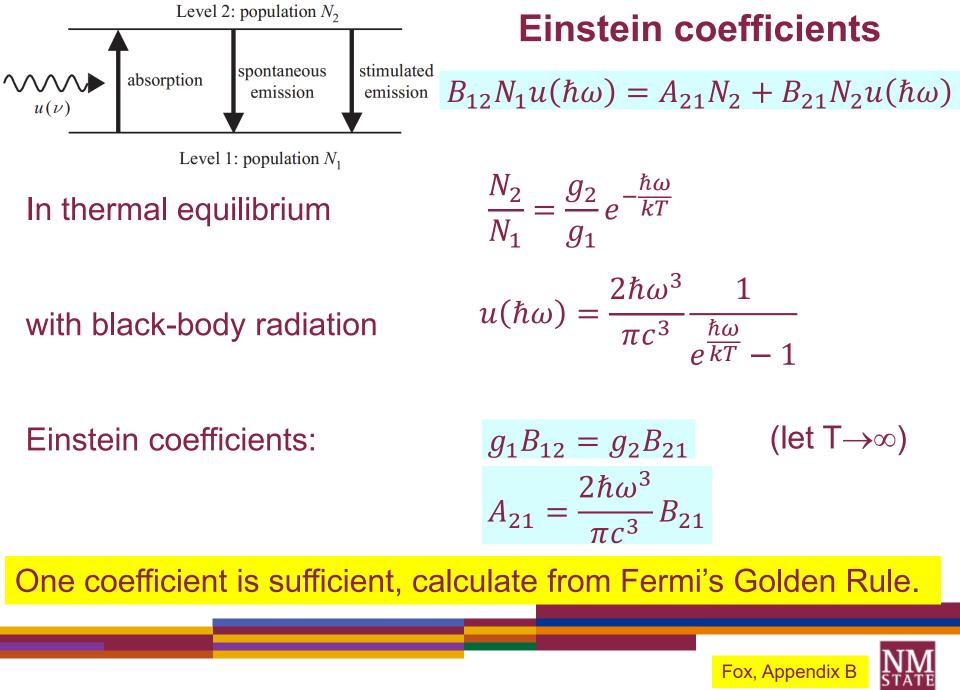


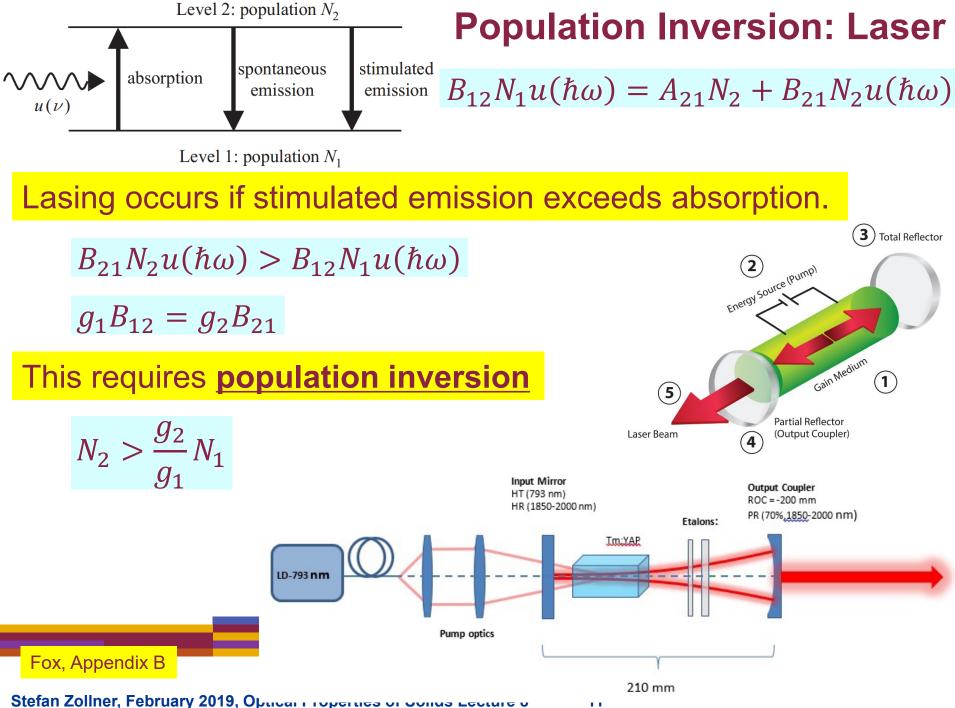
In equilibrium: N₁, N₂ constant. Absorption and emission balance.

 $B_{12}N_{1}u(\hbar\omega) = A_{21}N_{2} + B_{21}N_{2}u(\hbar\omega)$

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Fox, Appendix B





Fermi's Golden Rule: Momentum, dipole matrix element

$$\frac{1}{\tau} = \frac{2\pi}{\hbar} \int_{i,f} |\langle f | H_{eR} | i \rangle|^2 \delta (E_f - E_i - \hbar \omega) = \frac{2\pi}{\hbar} |\langle f | H_{eR} | i \rangle|^2 g_{fi}(\hbar \omega)$$

Interaction Hamiltonian:

Replace p with p-qAOnly keep linear terms in ACoulomb gauge: div A=0. Long-wavelength limit: $\lambda >>a$ Expand exponential exp(ik·r)=1 $E(t)=-dA/dt=i\omega A$ (A plane wave) Constant matrix element Joint density of states

$$H_{eR} = \frac{e}{m_0}\vec{p}\cdot\vec{A} = \frac{e}{m_0}\vec{p}\cdot\vec{A}_0$$

$$\langle f|H_{eR}|i\rangle = \frac{e}{m_0} \langle f|\vec{p}|i\rangle \cdot \vec{A}_0$$

Use **k**·**p** matrix element *P*

Fox, Appendix E

$$\vec{p} = m_0 \vec{v} = m_0 \frac{d\vec{r}}{dt} = \frac{im_0}{\hbar} [H_0, \vec{r}] = \frac{im_0}{\hbar} (H_0 \vec{r} - \vec{r} H_0) \quad \text{Ehrenfest theorem}$$

$$\frac{e}{m_0} \langle f | \vec{p} | i \rangle = \frac{ie}{\hbar} \langle f | H_0 \vec{r} - \vec{r} H_0 | i \rangle = \frac{ie}{\hbar} \langle f | E_f \vec{r} - \vec{r} E_i | i \rangle = i\omega_{fi} \langle f | e\vec{r} | i \rangle$$

Electric dipole interaction



Absorption selection rules for single electrons

 $\langle f | e \vec{r} | i
angle$

Quantum number	Selection rule	Polarization
Parity l m s m_s	changes $\Delta l = \pm 1$ $\Delta m = +1$ $\Delta m = -1$ $\Delta m = 0$ $\Delta m = \pm 1$ $\Delta s = 0$ $\Delta m_s = 0$	circular: σ^+ circular: σ^- linear: $\parallel z$ linear: $\parallel (x, y)$

Selection rules are approximate in low-symmetry crystals for $k \neq 0$.

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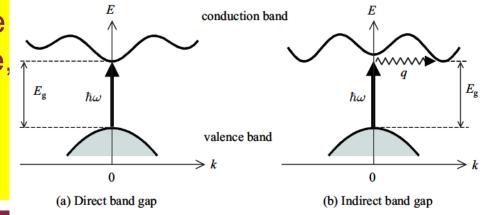
Fox, Appendix B

Matrix element for direct transitions in a solid

$$\begin{split} \langle f | H_{eR} | i \rangle &= \frac{e}{m_0} \langle f | \vec{p} | i \rangle \cdot \vec{A} = i \omega_{fi} \langle f | e \vec{r} | i \rangle \cdot \vec{A} = \langle f | e \vec{r} | i \rangle \cdot \vec{E}_0 \\ \\ \text{Bloch's Theorem:} & \vec{E} = -\frac{d \vec{A}}{dt} = i \omega \vec{A} \\ \psi_f(\vec{r}) &= e^{i \vec{k}_f \cdot \vec{r}} u_f(\vec{r}) & \psi_i(\vec{r}) = e^{i \vec{k}_i \cdot \vec{r}} u_i(\vec{r}) \\ \langle f | H_{eR} | i \rangle &= \langle u_f | e \vec{r} | u_i \rangle \cdot \vec{E}_0 \delta\left(\vec{k}_f - \vec{k}_i\right) \end{split}$$

Optical interband transitions must be direct: $\Delta k=0$

Indirect transitions ($\Delta \mathbf{k} \neq 0$) require another particle (phonon, surface, defect, etc) to carry momentum. Indirect transitions require another matrix element.





Fox, Chapter 3

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Joint density of states (effective mass approximation)

Assume constant matrix element (independent of k)

$$\frac{1}{\tau} = \frac{2\pi}{\hbar} \int_{i,f} |\langle f|H_{eR}|i\rangle|^2 \delta(E_{fi} - \hbar\omega) = \frac{2\pi}{\hbar} |\langle f|H_{eR}|i\rangle|^2 g_{fi}(\hbar\omega)$$
$$g_{fi}(\hbar\omega) = \int_{i,f} \frac{d^3\vec{k}}{8\pi^3} \delta(E_{fi} - \hbar\omega) = \int_{i,f} dk \frac{4\pi k^2}{8\pi^3} \delta(E_{fi} - \hbar\omega)$$

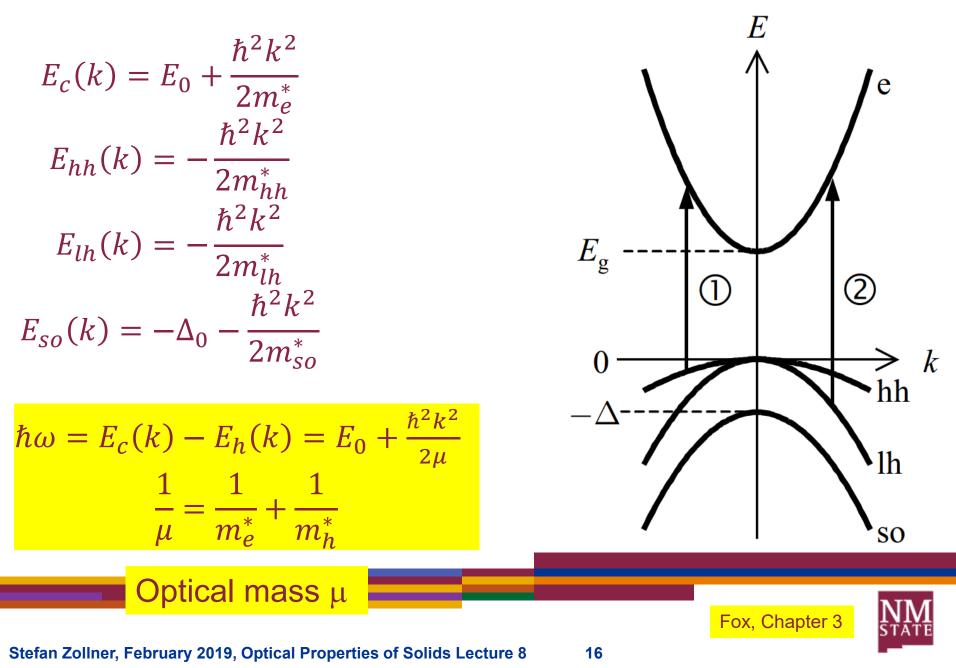
$$E = \frac{\hbar^2 k^2}{2m}, \qquad dE = \frac{\hbar^2 k dk}{m} \qquad \text{Consider two spin states}$$

$$g_{fi}(\hbar\omega) = \int_{i,f} dE \frac{1}{2\pi^2} \left(\frac{2m}{\hbar^2}\right)^{3/2} \sqrt{E} \delta(E_{fi} - \hbar\omega)$$

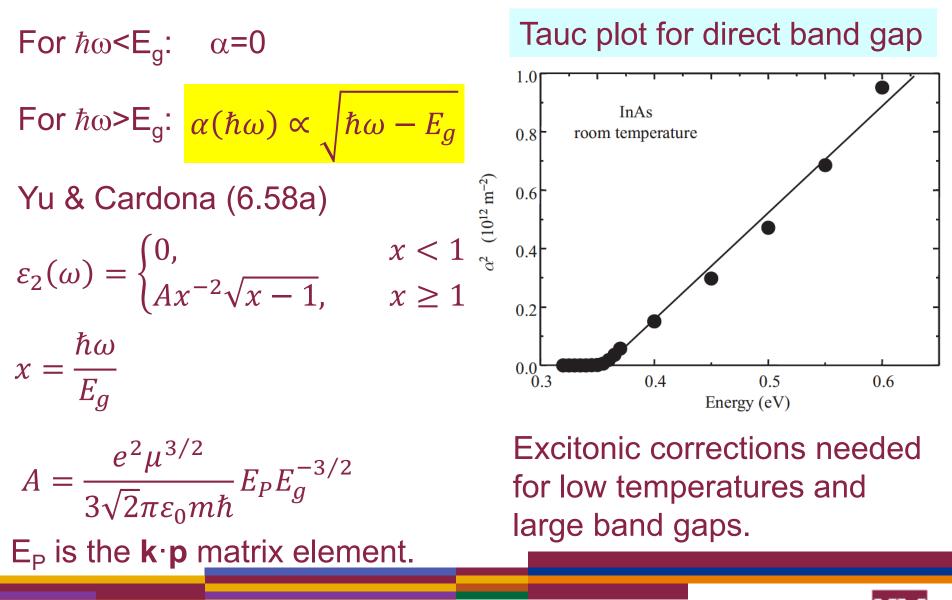
$$g_{fi}(\hbar\omega) = \frac{1}{2\pi^2} \left(\frac{2m_{fi}}{\hbar^2}\right)^{3/2} \sqrt{\hbar\omega - E_{fi}} \qquad \text{for } \hbar\omega > E_{fi}, 0 \text{ otherwise}$$
Joint density of states

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Optical (reduced) mass

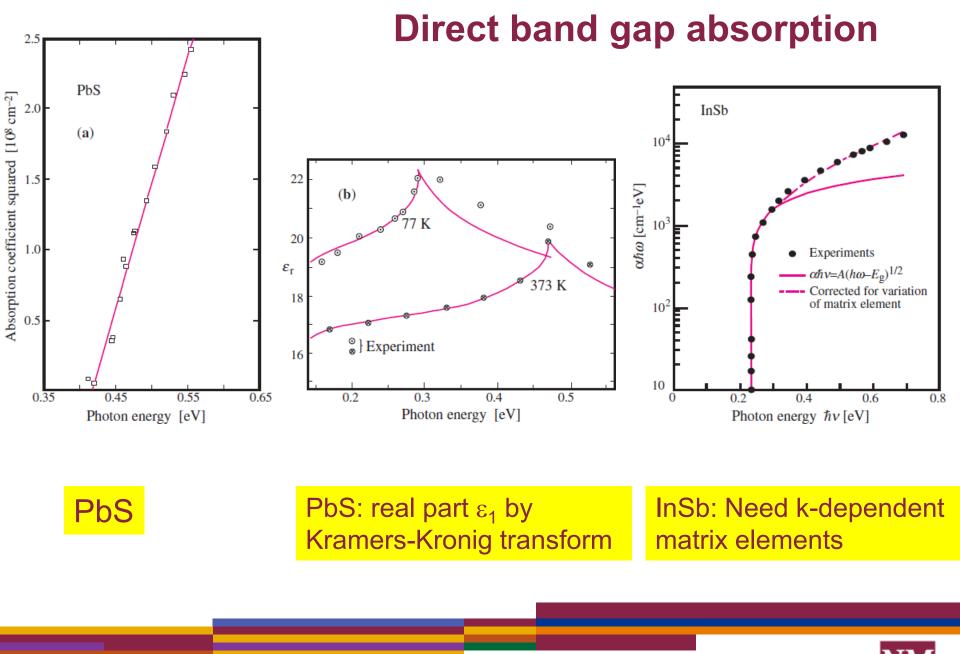


Direct band gap absorption





17



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Yu & Cardona

Summary (Lecture 8)

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